

STPS1045HR

Aerospace 2 x 10 A - 45 V Schottky rectifier

Datasheet - production data



Features

- Forward current: 2 x 10 A
- Repetitive peak voltage: 45 V
- Low forward voltage drop: 0.75 V
- Maximum junction temperature: 175 °C
- Negligible switching losses
- Low capacitance
- High reverse avalanche surge capability
- Hermetic package
- ESCC qualified

Description

This power Schottky rectifier is designed and packaged to comply with the ESCC5000 specification for aerospace products. Housed in a hermetically sealed surface mount package, it is ideal for use in applications for aerospace and other harsh environments.

The STPS1045HR is intended for use in medium voltage applications and in high frequency circuits where low switching losses and low noise are required.

Order code	ESCC detailed specification	Quality level	Configuration	Package	Lead finish	EPPL
STPS1045C2S1	-	Engineering model	Double die	SMD.5	Gold	-
STPS1045C2SG	5106/017/02	ESCC flight	common cathode			-

Table 1. Device summary

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1 Characteristics

Symbol	Characteristic	Value	Unit
I _{FSM}	Forward surge current (per diode) ⁽¹⁾	200	А
V_{RRM}	Repetitive peak reverse voltage ⁽²⁾	45	V
I _{RRM}	Repetitive peak reverse current ⁽³⁾	1	А
I _o	Average output rectified current (50% duty cycle): ⁽⁴⁾ per diode per device	10 20	A
I _{F(RMS)}	Forward rms current (per diode)	15	А
T _{OP}	Operating temperature range (case temperature)	-65 to +175	°C
TJ	Junction temperature	+175	°C
T_{STG}	Storage temperature range	-65 to +175	°C
T _{SOL}	Soldering temperature ⁽⁵⁾	+245	°C
dV/dt	Critical rate of rise of reverse voltage	10000	V/µs

Table 2. Absolute maximum ratings

1. Sinusoidal pulse of 10 ms duration

2. Pulsed, duration 5 ms, F = 50 Hz

3. Pulsed, duration 2 μ s, F = 1 kHz

4. For T_{case} > +140 °C, derate linearly to 0 A at +175 °C.

5. Duration 5 seconds maximum and the same package shall not be resoldered until 3 minutes have elapsed.

Table 3. Thermal resistance

Symbol	Characteristic	Value	Unit
$R_{th(j-c)}^{(1)}$	Thermal resistance, junction to case per diode per device ⁽²⁾	1.65 0.85	°C/W

1. Package mounted on infinite heatsink

2. The per device ratings apply only when both anode terminals are tied together.



Symbol Characteristic		MIL-STD-750	Test conditions	Val	Units	
Symbol	Characteristic	test method	Test conditions	Min.	Max.	Units
I _R	Reverse Current	4016	DC method, $V_R = 45V$	-	100	μA
V _{F1} ⁽¹⁾			Pulse method, I _F = 3 A	-	620	mV
V _{F2} ⁽¹⁾	Forward Voltage	4011	Pulse method, I _F = 20 A	-	750	mV
V _{F3} ⁽¹⁾			Pulse method, I _F = 20 A		880	mV
С	Capacitance	4001	V _R = 5 V, F = 1 MHz	-	500	pF
Z _{th(j-c)} ⁽²⁾	Relative thermal impedance, junction to case	3101	I_{H} = 15 to 40 A, t _H = 50 ms I_{M} = 50 mA, t _{md} = 100 µs		ulate F ⁽³⁾	°C/W

Table 4. Electrical measurements at ambiant temperature (per diode), $T_{amb} = 22 \pm 3$ °	perature (per diode), $T_{amb} = 22 \pm 3 \degree C$
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1. Pulse width \leq 300 µs, Duty Cycle \leq 2%

2. Performed only during screening tests parameter drift values (initial measurements), go-no-go

3. The limits for ΔVF shall be defined by the manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the $R_{th(j-c)}$ limits specified in maximum ratings.

Cumb al	Symbol Characteristic		Test conditions ⁽¹⁾	Values		Units
Symbol	Characteristic	test method	lest conditions.	Min.	Max.	Units
I _R	Reverse Current	4016	$T_{case} = +125 (+0, -5) °C$ DC method, V _R = 45 V	-	15	mA
V _{F1} ⁽²⁾			$T_{case} = +125 (+0, -5) °C$ pulse method, I _F = 3 A	-	570	mV
V (2)	V _{F2} ⁽²⁾ Forward Voltage	4011	$T_{case} = +125 (+0, -5) °C$ pulse method, I _F = 10 A	-	700	mV
V F2			$T_{case} = -55 (+0, -5) °C$ pulse method, I _F = 10 A	-	850	mV
V _{F3} ⁽²⁾			$T_{case} = +125 (+0, -5) °C$ pulse method, I _F = 20 A	-	800	mV

 Table 5. Electrical measurements at high and low temperatures (per diode)

1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.

2. Performed only during screening tests parameter drift values (initial measurements for HTRB), go-no-go.



2 Configuration





3 Package Information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

3.1 SMD.5 package information





Table 6. Surface mount SMD.5 mechanical data (3-terminal)

Reference	Dimension in	n millimeters	Dimensior	n in inches
Reference	Min.	Max.	Min.	Max.
А	2.84	3.15	0.112	0.124
A1	0.25	0.51	0.010	0.20
b	7.13	7.39	0.281	0.291
b1	5.58	5.84	0.220	0.230
b2 ⁽¹⁾	2.28	2.54	0.090	0.100
b3 ⁽¹⁾	2.92	3.18	0.115	0.125
D	10.03	10.28	0.395	0.405
D1 ⁽¹⁾	0.76	-	0.030	-
E	7.39	7.64	0.291	0.301
e ⁽¹⁾	1.91	BSC	0.0	075

1. 2 locations



4 Ordering Information

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Order code	ESCC detailed specification	Package	Lead finish	Marking	EPPL	Mass (g)	Packing
STPS1045C2S1	-	SMD.5	Gold	STPS1045C2S1	-	2.0	Strip
STPS1045C2SG	5106/017/02	SIVID.5	Gold	510601702	-	2.0	pack

Table 7. Ordering information

5 Revision history

Table 8	8.	Document	revision	history
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Date	Revision	Changes
16-June-2010	1	Initial release.
17-Dec-2013	2	Aligned terminal labels in Figure 1 and Figure 2.
01-Mar-2016	3	Updated Features, Figure 1, Table 1 and Table 7.



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